## DUAL POWER OPERATIONAL AMPLIFIERS

- OUTPUT CURRENT TO 1 A
- OPERATES AT LOW VOLTAGES
- SINGLE OR SPLIT SUPPLY
- LARGE COMMON-MODE AND DIFFERENTIAL MODE RANGE
- GROUND COMPATIBLE INPUTS
- LOW SATURATION VOLTAGE
- THERMAL SHUTDOWN


## DESCRIPTION

The L272 is a monolithic integrated circuits in Powerdip, Minidip and SO packages intended for use as power operational amplifiers in a wide range of applications including servo amplifiers and power supplies, compacts disc, VCR, etc.
The high gain and high output power capability provide superior performance whatever an operational amplifier/power booster combination is required.

PIN CONNECTIONS (top view)


## BLOCK DIAGRAMS



SCHEMATIC DIAGRAM (one only)


## ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{s}}$ | Supply Voltage | 28 | V |
| $\mathrm{~V}_{\mathrm{i}}$ | Input Voltage | $\mathrm{V}_{\mathrm{s}}$ |  |
| $\mathrm{V}_{\mathrm{i}}$ | Differential Input Voltage | $\pm \mathrm{V}_{\mathrm{s}}$ |  |
| $\mathrm{I}_{0}$ | DC Output Current | 1 | A |
| $\mathrm{I}_{\mathrm{p}}$ | Peak Output Current (non repetitive) | 1.5 | A |
| $\mathrm{P}_{\text {tot }}$ | Power Dissipation at: |  |  |
|  | $\mathrm{T}_{\text {amb }}=80^{\circ} \mathrm{C}$ (L272), $\mathrm{T}_{\text {amb }}=50^{\circ} \mathrm{C}(\mathrm{L} 272 \mathrm{M}), \mathrm{T}_{\text {case }}=90^{\circ} \mathrm{C}(\mathrm{L272D})$ <br> $\mathrm{T}_{\text {case }}=75^{\circ} \mathrm{C}($ L272 $)$ | 1.2 | D |
| $\mathrm{T}_{\text {op }}$ | Operating Temperature Range (L272D) | -40 to 85 | W |
| $\mathrm{~T}_{\text {stg }}, \mathrm{T}_{\mathrm{j}}$ | Storage and Junction Temperature | -40 to 150 | ${ }^{\circ} \mathrm{C}$ |

## THERMAL DATA

| Symbol |  | Parameter | Powerdip | SO16 | Minidip | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\text {th }} \mathrm{j}$-case | Thermal Resistance Junction-pins | Max. | 15 | - | ${ }^{*} 70$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\mathrm{th}} j$-amb | Thermal Resistance Junction-ambient | Max. | 70 | - | 100 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {th }} j$-alumina | Thermal Resistance Junction-alumina | Max. | - | ${ }^{* *} 50$ | - | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

* Thermal resistance junction-pin 4
* Thermal resistance junctions-pins with the chip soldered on the middle of an alumina supporting substrate measuring $15 \times 20 \mathrm{~mm} ; 0.65 \mathrm{~mm}$ thickness and infinite heatsink.

ELECTRICAL CHARACTERISTICS ( $\mathrm{V}=24 \mathrm{~V}, \mathrm{~T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{s}}$ | Supply Voltage |  | 4 |  | 28 | V |
| $\mathrm{I}_{\text {s }}$ | Quiescent Drain Current | $\begin{array}{ll} V_{\mathrm{O}}=\frac{\mathrm{V}_{\mathrm{S}}}{2} & \begin{array}{l} \mathrm{V}_{\mathrm{s}}=24 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{s}}=12 \mathrm{~V} \end{array} \end{array}$ |  | $\begin{gathered} 8 \\ 7.5 \end{gathered}$ | $\begin{aligned} & 12 \\ & 11 \end{aligned}$ | $\underset{\mathrm{mA}}{\mathrm{~mA}}$ |
| lb | Input Bias Current |  |  | 0.3 | 2.5 | $\mu \mathrm{A}$ |
| V os | Input Offset Voltage |  |  | 15 | 60 | mV |
| los | Input Offset Current |  |  | 50 | 250 | nA |
| SR | Slew Rate |  |  | 1 |  | V/us |
| B | Gain-bandwidth Product |  |  | 350 |  | kHz |
| $\mathrm{R}_{\mathrm{i}}$ | Input Resistance |  | 500 |  |  | $\mathrm{k} \Omega$ |
| $\mathrm{G}_{v}$ | O. L. Voltage Gain | $\begin{aligned} & f=100 \mathrm{~Hz} \\ & f=1 \mathrm{kHz} \end{aligned}$ | 60 | $\begin{aligned} & 70 \\ & 50 \end{aligned}$ |  | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \end{aligned}$ |
| eN | Input Noise Voltage | $\mathrm{B}=20 \mathrm{kHz}$ |  | 10 |  | $\mu \mathrm{V}$ |
| IN | Input Noise Current | $\mathrm{B}=20 \mathrm{kHz}$ |  | 200 |  | pA |
| CRR | Common Mode Rejection | $\mathrm{f}=1 \mathrm{kHz}$ | 60 | 75 |  | dB |
| SVR | Supply Voltage Rejection | $\begin{gathered} \mathrm{f}=100 \mathrm{~Hz}, \mathrm{R}_{\mathrm{G}}=10 \mathrm{k} \Omega, \mathrm{~V}_{\mathrm{R}}=0.5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{s}}=24 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{s}}= \pm 12 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{s}}= \pm 6 \mathrm{~V} \end{gathered}$ | 54 | $\begin{aligned} & 70 \\ & 62 \\ & 56 \end{aligned}$ |  | dB |
| V | Output Voltage Swing | $\begin{aligned} & I_{p}=0.1 \mathrm{~A} \\ & I_{p}=0.5 \mathrm{~A} \end{aligned}$ | 21 | $\begin{gathered} 23 \\ 22.5 \end{gathered}$ |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{C}_{\text {s }}$ | Channel Separation | $\begin{aligned} & \mathrm{f}=1 \mathrm{kHz} ; \mathrm{R}_{\mathrm{L}}=10 \Omega, \mathrm{G}_{\mathrm{v}}=30 \mathrm{~dB} \\ & \mathrm{~V}_{\mathrm{s}}=24 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{s}}= \pm 6 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 60 \\ & 60 \end{aligned}$ |  | dB |
| d | Distortion | $f=1 \mathrm{kHz}, \mathrm{G}_{\mathrm{v}}=3 \mathrm{~dB}, \mathrm{~V}_{\mathrm{s}}=24 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=\infty$ |  | 0.5 |  | \% |
| $\mathrm{T}_{\text {sd }}$ | Thermal Shutdown Junction Temperature |  |  | 145 |  | ${ }^{\circ} \mathrm{C}$ |

$\qquad$

Figure 1: Quiescent Current versus Supply Voltage


Figure 3: Open Loop Voltage Gain


Figure 5 : Output Voltage Swing versus Load Current


Figure 2 : Quiescent Drain Current versus Temperature


Figure 4 : Output Voltage Swing versus Load Current


Figure 6 : Supply Voltage Rejection versus Frequency


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Figure 7 : Channel Separation versus
Frequency


## APPLICATION SUGGESTION

## NOTE

In order to avoid possible instability occuring into final stage the usual suggestions for the linear power stages are useful, as for instance :

Figure 8 : Common Mode Rejection versus Frequency


- layout accuracy ;
- a 100 nF capacitor corrected between supply pins and ground ;
- boucherot cell ( 0.1 to $0.2 \mu \mathrm{~F}+1 \Omega$ series) between outputs and ground or across the load.

Figure 9 : Bidirectional DC Motor Control with $\mu$ P Compatible Inputs
ET,

Figure 10 : Servocontrol for Compact-disc
$\square$
Figure 11 : Capstan Motor Control in Video Recorders

$\qquad$

Figure 12 : Motor Current Control Circuit.


Figure 13 : Bidirectional Speed Control of DC Motors.
For circuit stability ensure that $R_{x}>\frac{2 R 3 \circ R 1}{R_{M}}$ where $R_{M}=$ internal resistance of motor.
The voltage available at the terminals of the motor is $V_{M}=2\left(V_{i} \cdot \frac{V_{s}}{2}\right)+\left|R_{0}\right| \cdot I M$ where $\left|R_{0}\right|=\frac{2 R \circ R 1}{R_{X}}$ and $\mathrm{I}_{\mathrm{M}}$ is the motor current.


POWERDIP 16 PACKAGE MECHANICAL DATA

| DIM. | mm |  |  | inch |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| a1 | 0.51 |  |  | 0.020 |  |  |
| B | 0.85 |  | 1.40 | 0.033 |  | 0.055 |
| b |  | 0.50 |  |  | 0.020 |  |
| b1 | 0.38 |  | 0.50 | 0.015 |  | 0.020 |
| D |  |  | 20.0 |  | 0.346 | 0.787 |
| E |  | 2.54 |  |  | 0.100 |  |
| e |  | 17.78 |  |  |  |  |
| e3 |  |  | 7.10 |  |  | 0.280 |
| F |  |  | 5.10 |  | 0.130 | 0.201 |
| I |  |  |  |  |  |  |
| L |  |  |  |  |  |  |
| Z |  |  |  |  |  |  |



MINIDIP PACKAGE MECHANICAL DATA

| DIM. | mm |  |  | inch |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A |  | 3.32 |  |  | 0.131 |  |
| a1 | 0.51 |  |  | 0.020 |  |  |
| B | 1.15 |  | 1.65 | 0.045 |  | 0.065 |
| b | 0.356 |  | 0.55 | 0.014 |  | 0.022 |
| b1 | 0.204 |  | 0.304 | 0.008 |  | 0.012 |
| D |  |  | 10.92 |  |  | 0.430 |
| E | 7.95 |  | 9.75 | 0.313 |  | 0.384 |
| e |  | 2.54 |  |  | 0.100 |  |
| e3 |  | 7.62 |  |  | 0.300 |  |
| e4 |  | 7.62 |  |  | 0.300 |  |
| F |  |  | 6.6 |  |  | 0.260 |
| I |  |  | 5.08 |  |  | 0.200 |
| L | 3.18 |  | 3.81 | 0.125 |  | 0.150 |
| Z |  |  | 1.52 |  |  | 0.060 |



## S016 NARROW PACKAGE MECHANICAL DATA

| DIM. | mm |  |  | inch |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A |  |  | 1.75 |  |  | 0.069 |
| a1 | 0.1 |  | 0.25 | 0.004 |  | 0.009 |
| a2 |  |  | 1.6 |  |  | 0.063 |
| b | 0.35 |  | 0.46 | 0.014 |  | 0.018 |
| b1 | 0.19 |  | 0.25 | 0.007 |  | 0.010 |
| C |  | 0.5 |  |  | 0.020 |  |
| c1 | $45^{\circ}$ (typ.) |  |  |  |  |  |
| D | 9.8 |  | 10 | 0.386 |  | 0.394 |
| E | 5.8 |  | 6.2 | 0.228 |  | 0.244 |
| e |  | 1.27 |  |  | 0.050 |  |
| e3 |  | 8.89 |  |  | 0.350 |  |
| F | 3.8 |  | 4.0 | 0.150 |  | 0.157 |
| L | 0.4 |  | 1.27 | 0.150 |  | 0.050 |
| M |  |  | 0.62 |  |  | 0.024 |
| S | $8^{\circ}$ (max.) |  |  |  |  |  |



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